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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Bryant et al.

Examiner: Lewis, Monica

Scrial No.: 09/682,957

Art Unit: 2822

Filed: 11/2/2001

For: TRANSISTOR STRUCTURE WITH THICK RECESSED SOURCE/DRAIN STRUCTURES AND FABRICATION PROCESS OF SAME

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Request for Reconsideration

Sir:

This Request for reconsideration is in response to the Office Action mailed July 29,

2004.

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